

TECHNICAL DATA SHEET

6 Lake Street, Lawrence, MA 01841 1-800-446-1158 / (978) 620-2600 / Fax: (978) 689-0803 Website: http: //www.microsemi.com

## NPN SILICON TRANSISTOR

Qualified per MIL-PRF-19500/317

DEVICES 2N2369A 2N2369AU 2N2369AUA * Available to JANS quality	2N2369A 2N2369A y level only.	-		14449		LEVELS JAN JANTX JANTXV JANS
ABSOLUTE MAXIMUM						
Parameters / Test Conditions		Syr	nbol	Value	Unit	
Collector-Emitter Voltage	2N2369A / U / UA 2N4449 / UB / UBC	V	CEO	15 20	Vdc	
Emitter-Base Voltage	2N2369A / U / UA 2N4449 / UB / UBC	V	EBO	4.5 6.0	Vdc	TO-18 (TO-206AA) 2N2369A
Collector-Base Voltage			СВО	40	Vdc	
Collector-Emitter Voltage		I	CES	40	Vdc	
Total Power Dissipation @ $T_A = +25^{\circ}C$	2N2369A; 2N4449 UA, UB, UBC U	I	P <sub>T</sub>	$\begin{array}{c} 0.36 {}^{(1)} \\ 0.36 {}^{(1, 5)} \\ 0.50 {}^{(4)} \end{array}$	W	
Operating & Storage Junction	Femperature Range	T <sub>op</sub>	, T <sub>stg</sub>	-65 to +200	°C	TO-46 (TO-206AB) 2N4449
THERMAL CHARACTE	RISTICS					$\frown$
Parameters / Tes	t Conditions	Syr	nbol	Value	Unit	
Thermal Resistance, Ambie	nt-to-Case					
2N2369A; 2N4449 UA, UB, UBC U		R	θJA	400 400 <sup>(5)</sup> 350	°C/W	SURFACE MOUNT UA
<ol> <li>Derate linearly 4.76 i</li> <li>Derate linearly 3.08 i</li> <li>Derate linearly 3.44 i</li> </ol>	nW°/C above $T_A = +25^\circ$ nW°/C above $T_C = +95^\circ$ nW°/C above $T_C = +70^\circ$ nW°/C above $T_A = +54.5^\circ$ CB (1Oz. Cu) with contact <b>TERISTICS</b> ( $T_A = +25^\circ$	C. C. i°C. ts 20 mils	-	n package pade	<u>.</u>	SURFACE MOUNT UB & UBC (UBC = Ceramic Lid Version)
Parameters / Test Co	nditions Sy	mbol	Min.	Max.	Unit	(vor
OFF CHARACTERTICS					<u> </u>	
Collector-Emitter Breakdown V $I_C = 10$ mAdc	Voltage V <sub>(E</sub>	R)CEO	15		Vdc	SURFACE MOUNT
Collector-Base Cutoff Current	1					SUNFACE MOUNT



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#### ELECTRICAL CHARACTERISTICS ( $T_A = +25^{\circ}C$ , unless otherwise noted)

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS				
Emitter-Base Breakdown Voltage $V_{EB} = 4.5$ Vdc Emitter-Base Cutoff Current	I <sub>EBO</sub>		10	μAdc
$V_{EB} = 4.0 V dc$			0.25	
Collector- Base Breakdown Voltage $V_{CB} = 40$ Vdc Collector-Base Cutoff Current	I <sub>CBO</sub>		10	μAdc
$V_{CB} = 32 V dc$			0.2	
ON CHARACTERISTICS (1)				
Forward-Current Transfer Ratio $I_C = 10mAdc, V_{CE} = 0.35Vdc$ $I_C = 30mAdc, V_{CE} = 0.4Vdc$ $I_C = 10mAdc, V_{CE} = 1.0Vdc$ $I_C = 100mAdc, V_{CE} = 1.0Vdc$	h <sub>FE</sub>	40 30 40 20	120 120 120 120	
Collector-Emitter Saturation Voltage $I_C = 10mAdc$ , $I_B = 1.0mAdc$ $I_C = 30mAdc$ , $I_B = 3.0mAdc$ $I_C = 100mAdc$ , $I_B = 10mAdc$	V <sub>CE(sat)</sub>		0.20 0.25 0.45	Vdc
Base-Emitter Saturation Voltage $I_C = 10mAdc, I_B = 1.0mAdc$ $I_C = 30mAdc, I_B = 3.0mAdc$ $I_C = 100mAdc, I_B = 10mAdc$	V <sub>BE(sat)</sub>	0.70 0.80	0.85 0.90 1.20	Vdc

#### **DYNAMIC CHARACTERISTICS**

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Forward Current Transfer Ratio $I_C = 10mAdc, V_{CE} = 10Vdc, f = 100MHz$	h <sub>fe</sub>	5.0	10	
Output Capacitance	C <sub>obo</sub>		4.0	pF
$V_{CB}=5.0Vdc,I_{E}=0,100kHz\leq f\leq 1.0MHz$	C <sub>obo</sub>		4.0	рі
Input Capacitance	C		5.0	πD
$V_{EB}=0.5Vdc,I_C=0,100kHz\leq f\leq 1.0MHz$	$C_{ibo}$		5.0	pF

#### SWITCHING CHARACTERISTICS

Parameters / Test Conditions	Symbol	Min.	Max.	Unit
Turn-On Time $I_C = 10mAdc; I_{B1} = 3.0mAdc, I_{B2} = -1.5mAdc$	t <sub>on</sub>		12	ηs
Turn-Off Time $I_C = 10mAdc; I_{B1} = 3.0mAdc, I_{B2} = -1.5mAdc$	t <sub>off</sub>		18	ηs
Charge Storage Time $I_C = 10mAdc$ ; $I_{B1} = 10mAdc$ , $I_{B2} = 10mAdc$	t <sub>S</sub>		13	ηs

(1) Pulse Test: Pulse Width =  $300\mu s$ , Duty Cycle  $\leq 2.0\%$ .

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